NSN 5962-01-206-1987



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-206-1987 **Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 853.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Ea-6b acft **Features Provided:** Electrostatic sensitive and schottky and 2-state output and programmed and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Case Outline Source And Designator:** D-8 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Prom **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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